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BFR92A NPN 5 GHz wideband transistor Rev. 04 – 2 March 2009

**Product data sheet** 

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NXP Semiconductors



#### FEATURES

- High power gain
- Low noise figure
- Low intermodulation distortion.

#### APPLICATIONS

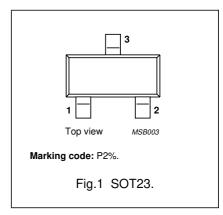
• RF wideband amplifiers and oscillators.

#### DESCRIPTION

NPN wideband transistor in a plastic SOT23 package. PNP complement: BFT92.

#### PINNING

PIN	DESCRIPTION		
1	base		
2	emitter		
3	collector		



#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage		_	20	V
V <sub>CEO</sub>	collector-emitter voltage		-	15	V
I <sub>C</sub>	collector current (DC)		-	25	mA
P <sub>tot</sub>	total power dissipation	$T_s \le 95 \ ^{\circ}C$	-	300	mW
C <sub>re</sub>	feedback capacitance	$I_{C} = i_{c} = 0; V_{CE} = 10 V; f = 1 MHz$	0.35	-	pF
f <sub>T</sub>	transition frequency	I <sub>C</sub> = 15 mA; V <sub>CE</sub> = 10 V; f = 500 MHz	5	-	GHz
G <sub>UM</sub>	maximum unilateral power gain	$I_{C}$ = 15 mA; $V_{CE}$ = 10 V; f = 1 GHz; $T_{amb}$ = 25 °C	14	-	dB
		$I_{C}$ = 15 mA; $V_{CE}$ = 10 V; f = 2 GHz; $T_{amb}$ = 25 °C	8	-	dB
F	noise figure	$I_{C} = 5 \text{ mA}; V_{CE} = 10 \text{ V}; f = 1 \text{ GHz};$ $\Gamma_{s} = \Gamma_{opt}; T_{amb} = 25 \text{ °C}$	2.1	-	dB
V <sub>O</sub>	output voltage		150	-	mV

#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	_	20	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	15	V
V <sub>EBO</sub>	emitter-base voltage	open collector	_	2	V
I <sub>C</sub>	collector current (DC)		_	25	mA
P <sub>tot</sub>	total power dissipation	$T_s \le 95 \text{ °C}$ ; note 1; see Fig.3	-	300	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	175	°C

#### Note

1.  $\ T_s$  is the temperature at the soldering point of the collector pin.

#### BFR92A

#### **THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-s</sub>	thermal resistance from junction to soldering point	$T_s \le 95 \ ^\circ C$ ; note 1	260	K/W

#### Note

1. T<sub>s</sub> is the temperature at the soldering point of the collector pin.

#### **CHARACTERISTICS**

T<sub>i</sub> = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector leakage current	$I_E = 0; V_{CB} = 10 V$	-	-	50	nA
h <sub>FE</sub>	DC current gain	$I_{C} = 15 \text{ mA}; V_{CE} = 10 \text{ V}; \text{ see Fig.4}$	65	90	135	
C <sub>c</sub>	collector capacitance	$I_E = i_e = 0; V_{CB} = 10 \text{ V}; f = 1 \text{ MHz};$ see Fig.5	-	0.6	_	pF
C <sub>e</sub>	emitter capacitance	$I_{C} = i_{c} = 0; V_{EB} = 10 V; f = 1 MHz$	-	1.2	-	pF
C <sub>re</sub>	feedback capacitance	$I_{C} = i_{c} = 0; V_{CE} = 10 V; f = 1 MHz$	-	0.35	-	pF
f <sub>T</sub>	transition frequency	$I_{C} = 15 \text{ mA}; V_{CE} = 10 \text{ V}; f = 500 \text{ MHz};$ see Fig.6	-	5	-	GHz
G <sub>UM</sub>	maximum unilateral power gain (note 1)	$I_{C} = 15 \text{ mA}; V_{CE} = 10 \text{ V}; f = 1 \text{ GHz};$ $T_{amb} = 25 \text{ °C}$	-	14	-	dB
		$I_{C} = 15 \text{ mA}; V_{CE} = 10 \text{ V}; f = 2 \text{ GHz};$ $T_{amb} = 25 \text{ °C}$	-	8	-	dB
F	noise figure	$\label{eq:lc} \begin{array}{l} I_C = 5 \text{ mA}; \ V_{CE} = 10 \text{ V}; \ f = 1 \text{ GHz}; \\ \Gamma_s = \Gamma_{opt}; \ T_{amb} = 25 \ ^\circ\text{C}; \\ \text{see Figs 13 and 14} \end{array}$	-	2.1	_	dB
		$\label{eq:lc} \begin{array}{l} I_C = 5 \text{ mA; } V_{CE} = 10 \text{ V; } f = 2 \text{ GHz;} \\ \Gamma_s = \Gamma_{opt} \text{; } T_{amb} = 25 \ ^\circ\text{C;} \\ \text{see Figs 13 and 14} \end{array}$	-	3	-	dB
Vo	output voltage	notes 2 and 3	-	150	_	mV
d <sub>2</sub>	second order intermodulation distortion	notes 2 and 4; see Fig.16	-	-50	-	dB

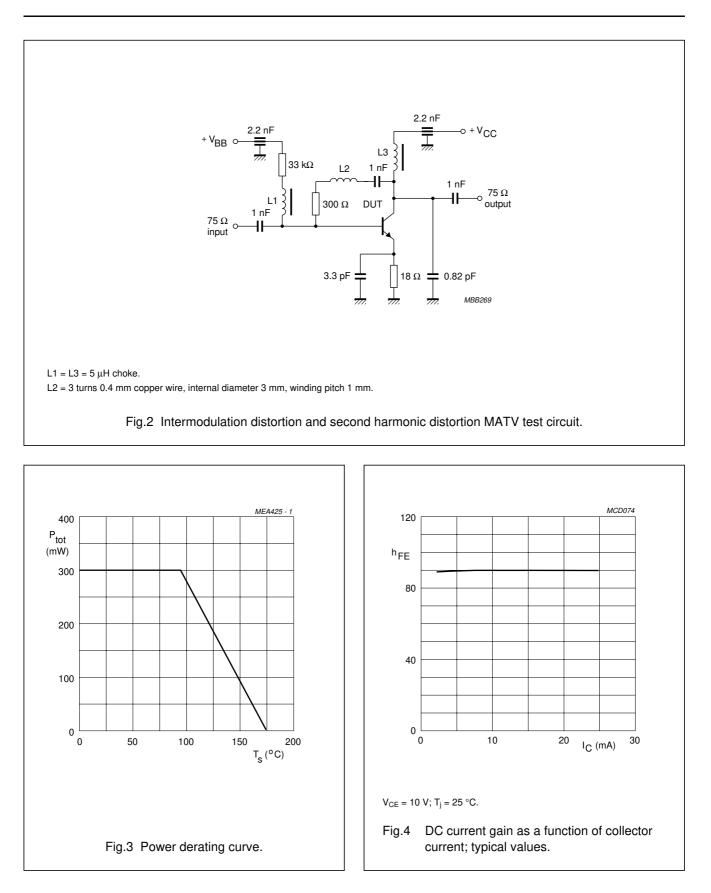
#### Notes

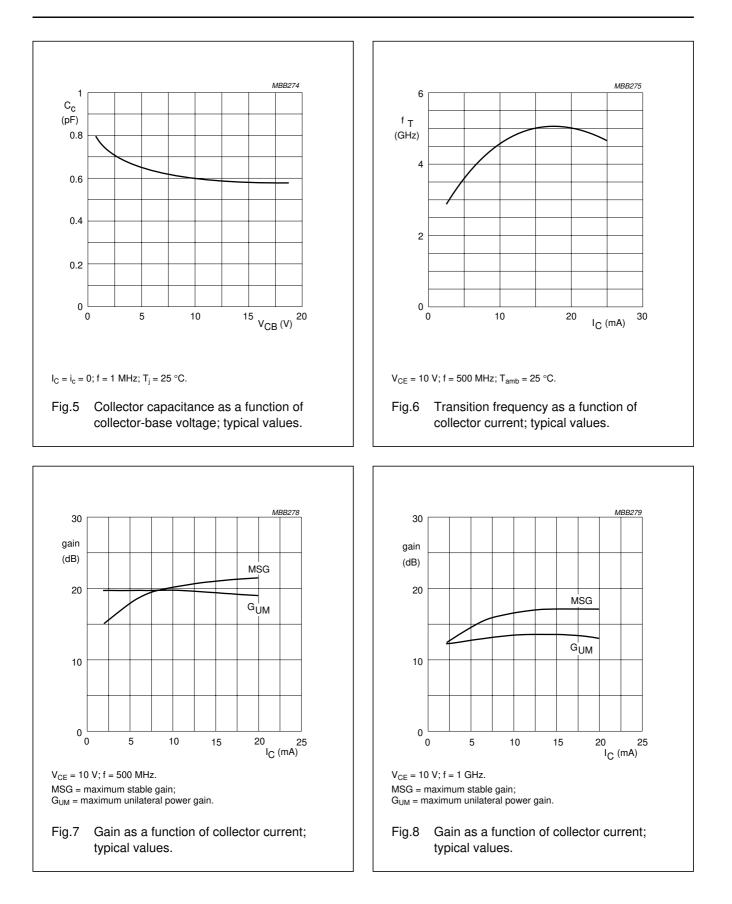
1.  $G_{UM}$  is the maximum unilateral power gain, assuming  $S_{12}$  is zero and  $G_{UM} = 10 \log \frac{|S_{21}|^2}{(1 - |S_{11}|^2)(1 - |S_{22}|^2)} d\dot{B}$ .

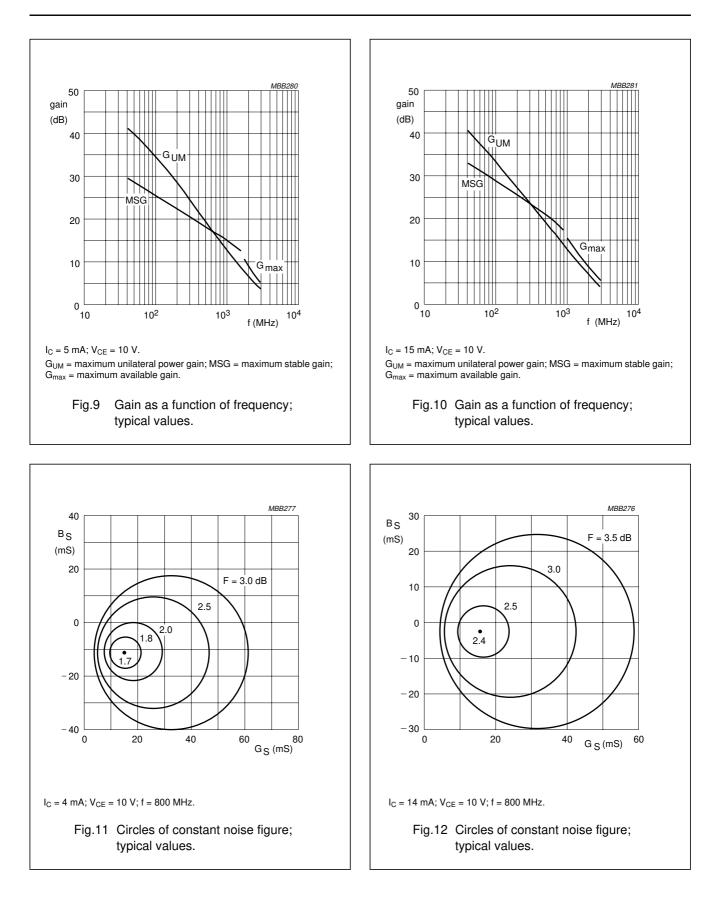
2. Measured on the same die in a SOT37 package (BFR90A).

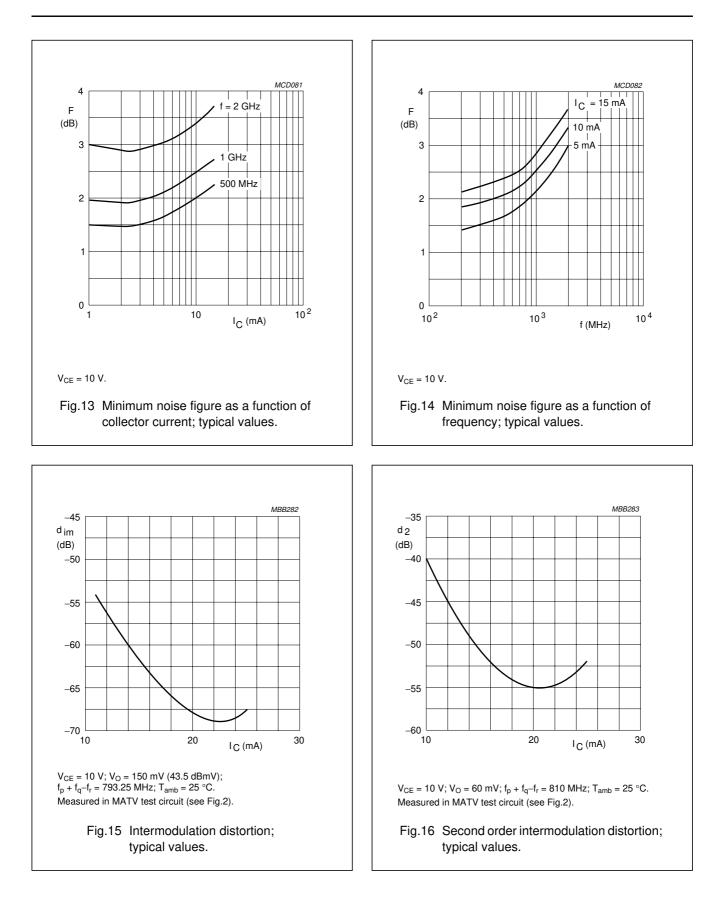
3.  $d_{im} = -60 \text{ dB} \text{ (DIN 45004B)}; I_C = 14 \text{ mA}; V_{CE} = 10 \text{ V}; R_L = 75 \Omega; \text{VSWR} < 2; T_{amb} = 25 \text{ °C}$  $V_p$  =  $V_O$  at  $d_{im}$  =  $-60~dB;\,f_p$  = 795.25 MHz;  $V_{q} = V_{O} - 6 \text{ dB}; f_{q} = 803.25 \text{ MHz};$  $V_r = V_O - 6 \text{ dB}; f_r = 805.25 \text{ MHz};$ measured at  $f_p + f_q - f_r = 793.25$  MHz.

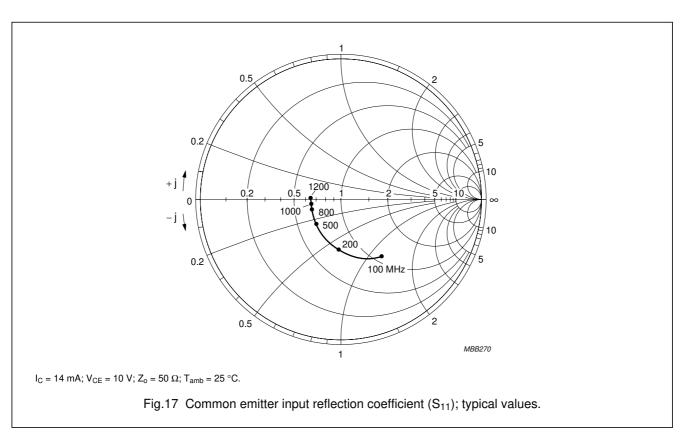
4.  $I_C = 14 \text{ mA}; V_{CE} = 10 \text{ V}; R_L = 75 \Omega; \text{VSWR} < 2; T_{amb} = 25 \text{ °C}$  $V_p = 60 \text{ mV}$  at  $f_p = 250 \text{ MHz}$ ;  $V_q = 60 \text{ mV}$  at  $f_q = 560 \text{ MHz}$ ; measured at  $f_p + f_q = 810$  MHz.

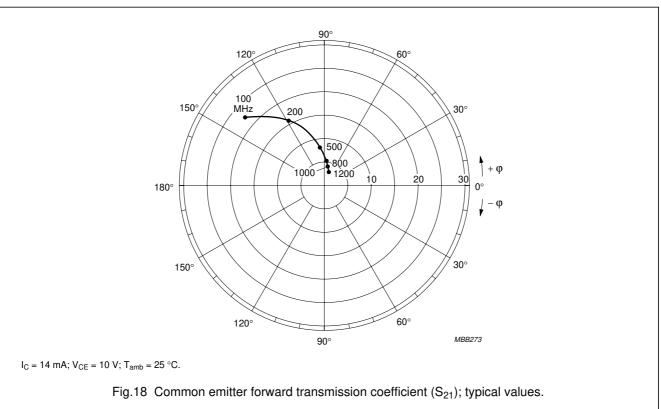


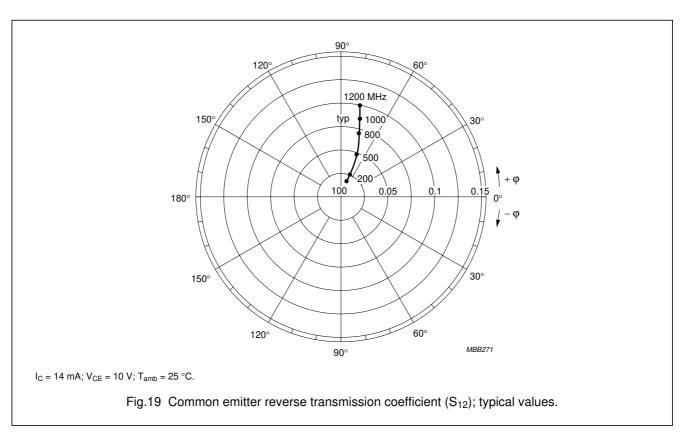


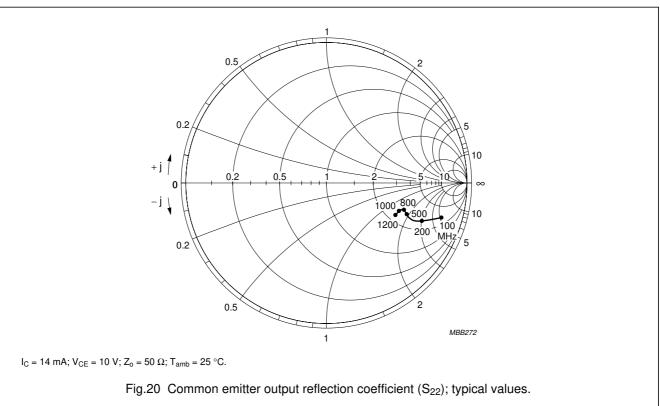








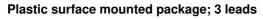


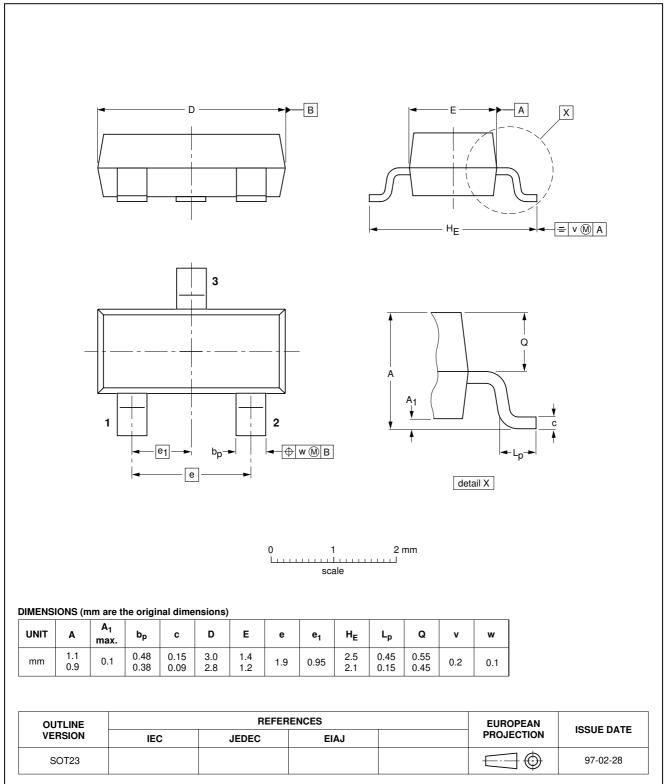


BFR92A

## NPN 5 GHz wideband transistor

#### PACKAGE OUTLINE





SOT23

## Legal information

#### Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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## **Revision history**

Document ID	Delessa data			
Document	Release date	Data sheet status	Change notice	Supersedes
BFR92A_N_4	20090302	Product data sheet	-	BFR92A_N_3
Modifications:	<ul> <li>Fig.1 on page</li> </ul>	2; Figure note changed		
BFR92A_N_3	20080307	Product data sheet	-	BFR92A_2
BFR92A_2 (9397 750 02766)	19971029	Product specification	-	BFR92A_1
BFR92A_1	19950901	-	-	-

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